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COMPLIANT

HALOGEN

FREE

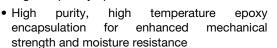
High Performance Schottky Rectifier, 2 x 30 A

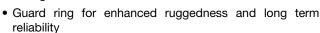


PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 30 A							
V_{R}	35 V, 40 V, 45 V							
V _F at I _F	0.53 V							
I _{RM} max.	250 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	20 mJ							
Package	TO-220AB 3L							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform (per device)	60	А					
V _{RRM}		35 to 45	V					
I _{FRM}	T _C = 113 °C (per leg)	60	^					
I _{FSM}	t _p = 5 µs sine	1500	A					
V _F	30 A _{pk} , T _J = 125 °C	0.53	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-60CTQ035-M3 VS-60CTQ040-M3 VS-60CTQ045-M3 UNITS								
Maximum DC reverse voltage	V_R	35	40	ΛE	V			
Maximum working peak reverse voltage	V_{RWM}	33	40	45	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS				
Maximum average forward per leg		50 % duty cycle at T _C = 113 °C, rectangular waveform		30	A			
current per device	I _{F(AV)}			60				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 113 °C		60				
Maximum peak one cycle non-repetitive	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500				
surge current per leg		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	300				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.40 mH		20	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	Α			



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS			
		30 A	T _J = 25 °C	0.51	0.56	V		
Maximum forward valtage drap	V _{FM} ⁽¹⁾	60 A	1j=25 C	0.66	0.72			
Maximum forward voltage drop		30 A	T _{.1} = 125 °C	0.48	0.53			
		60 A	1	0.68	0.75			
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	Rated DC voltage	0.33	2	mA		
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	145	250	IIIA		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	20	00	pF			
Typical series inductance	L _S	Measured from top of term	8.0		nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000		V/µs			

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range		TJ		-65 to +150	°C				
Maximum storage temperate	ıre range	T _{Stg}		-65 to +175	C				
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	1.2	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	O/VV				
Annyayimata waisht				2	g				
Approximate weight				0.07	OZ.				
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque	maximum		Non-lubricated trireads	12 (10)	(lbf · in)				
Marking device				60CT	Q035				
			Case style TO-220AB 3L	60CT	Q040				
					60CTQ045				

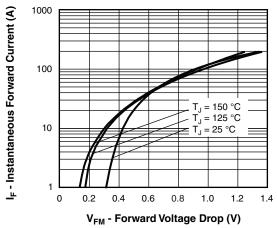


Fig. 1 - Maximum Forward Voltage Drop Characteristics

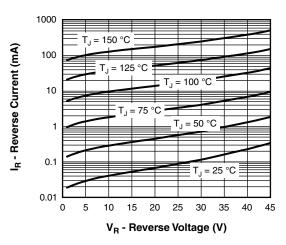


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

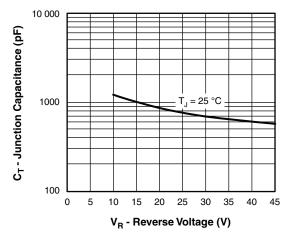


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

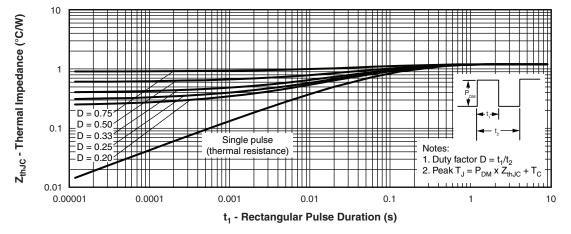


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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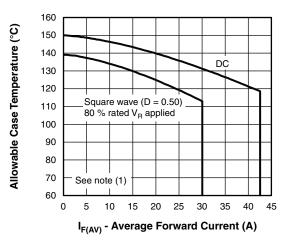


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

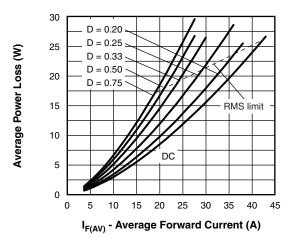


Fig. 6 - Forward Power Loss Characteristics

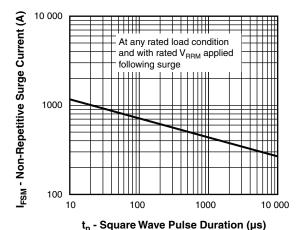


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

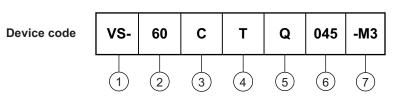
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

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ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

3 - Circuit configuration

C = common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

035 = 35 V

6 - Voltage ratings

040 = 40 V 045 = 45 V

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-60CTQ035-M3	50	Antistatic plastic tubes						
VS-60CTQ040-M3	50	Antistatic plastic tubes						
VS-60CTQ045-M3	50	Antistatic plastic tubes						

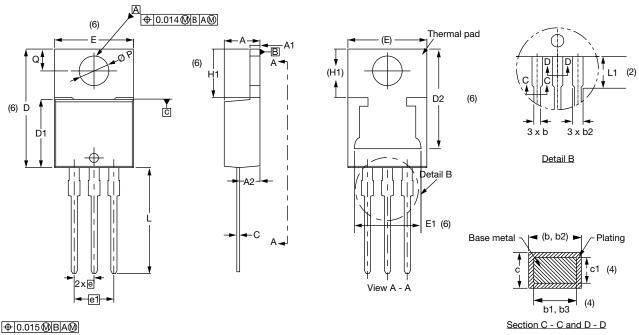
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96154						
Part marking information	www.vishay.com/doc?95028						

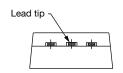


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TO-220AB 3L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		HES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355								

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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